

Memory Product Specification

DDR2- 1066 Overclocking Unbuffered DIMM

Description

The Module is DDR2-1066 CL5 over clocking Unbuffered Memory module. The Module density from 512MB to 2GB, it consists DDR2-1066MHz low latency Synchronous DRAMs in FBGA packages, Memory Module intended for mounting into 240-pin edge connector sockets. The electrical and mechanical specifications are as follows

Features

- JEDEC Standard
- DDR2 Speed Grade : 1066Mbps
- Unbuffered DIMM : 240-pin
- Memory Organization : x8 FBGA DRAM chip
- DDR2 DRAM interface : SSTL_18
- CAS latency : 5-5-5-15
- Bandwidth : 8500MB/s
- VDD voltage : 2.2V
- VDDQ voltage : 2.2V
- Serial presence detect with EEPROM.
- PCB height : **1.18 inch**
- RoHS Compliant
- Application : Gaming player